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- 3-State Outputs Drive Bus Lines or Buffer Memory Address Registers
- P-N-P Inputs Reduce D-C Loading
- Hysteresis at Inputs Improves Noise Margins
- Data Flow-thru Pinout (All Inputs on Opposite Side from Outputs)

description

These octal buffers and line drivers are designed to have the performance of the popular SN54LS240/SN74LS240 series and, at the same time, offer a pinout having the inputs and outputs on opposite sides of the package. This arrangement greatly enhances printed circuit board layout.

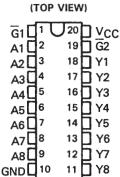
The three-state control gate is a 2-input NOR such that if either $\overline{G1}$ or $\overline{G2}$ are high, all eight outputs are in the high-impedance state.

The 'LS540 offers inverting data and the 'LS541 offers true data at the outputs.

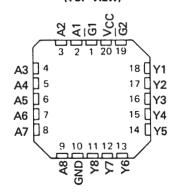
The SN54LS540 and SN54LS541 are characterized for operation over the full military temperature range of -55° C to 125° C. The SN74LS540 and SN74LS541 are characterized for operation from 0° C to 70° C.

TYPE	RATED	RATED	TYPICAL POWER				
	[†] OL	¹он	DISSIP	ATION			
	(SINK	(SOURCE	(ENAB	LED)			
	CURRENT)	CURRENT)	'LS540	'LS541			
SN54LS'	12 mA	- 12 mA	92.5 mW	120 mW			
SN74LS'	24 mA	- 15 mA	92.5 mW	120 mW			

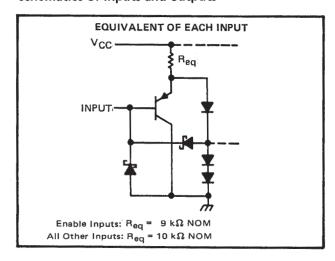
SN54LS540, SN54LS541 . . . J OR W PACKAGE SN74LS540, SN74LS541 . . . DW OR N PACKAGE

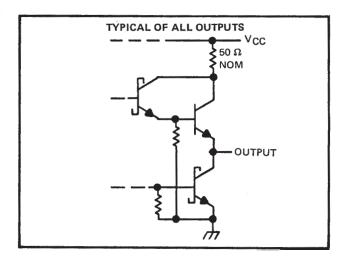


SN54LS540, SN54LS541 . . . FK PACKAGE (TOP VIEW)



schematics of inputs and outputs





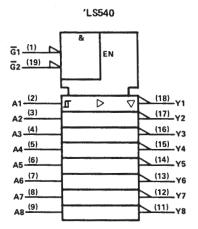
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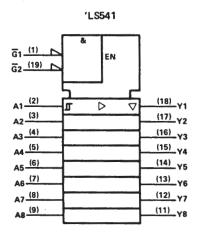


SN54LS540, SN54LS541, SN74LS540, SN74LS541 OCTAL BUFFERS AND LINE DRIVERS WITH 3-STATE OUTPUTS

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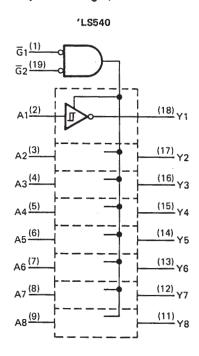
logic symbols†

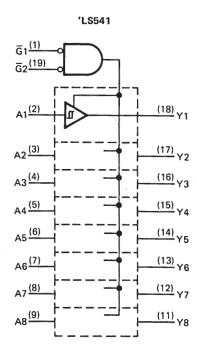




[†] These symbols are in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)





absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, VCC (see Note 1)		 7 V
Input voltage		 7 V
Operating free-air temperature range	SN54LS540, SN54LS541	 – 55°C to 125°C
		0°C to 70°C
Storage temperature range		 \dots 65°C to 150°C

NOTE 1: Voltage values are with respect to the network ground terminal.



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recommended operating conditions

DADAMETED		SN54LS'			SN74LS'		
PARAMETER		NOM	MAX	MIN	NOM	MAX	UNIT
Supply voltage, V _{CC} (see Note 1)	4.5	5	5.5	4.75	5	5.25	V
High-level output current, IOH			-12			- 15	mA
Low-level output current, IOL			12			24	mA
Operating free-air temperature, TA	- 55		125	0		70	°C

NOTE 1: Voltage values are with respect to network ground terminal.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER			TEST CONDITIONS†		SN54LS'			SN74LS'			UNIT
		TEST CONDITIONS.		MIN	TYP [‡]	MAX	MIN	TYP [‡]	MAX	UNII	
VIH	High-level input volta	age			2			2			V
VIL	Low-level input volta	ige					0.6			0.6	V
VIK	Input clamp voltage		V _{CC} = MIN,	I _I = -18 mA			- 1.5			- 1.5	V
	Hysteresis (V _{T+} -	V _T _)	VCC = MIN		0.2	0.4		0.2	0.4		V
VOH High-level output voltage		$V_{CC} = MIN,$ $V_{IL} = V_{IL} max,$	$V_{IH} = 2 V$, $I_{OH} = -3 \text{ mA}$	2.4	3.4		2.4	3.4		V	
		itage	$V_{CC} = MIN,$ $V_{IL} = 0.5 V,$	$V_{IH} = 2V,$ $I_{OH} = MAX$	2			2			V
VOL	Low-level output vo	tage	$V_{CC} = MIN,$ $V_{IH} = 2 V,$	I _{OL} = 12 mA		0.25	0.4		0.25	0.4	V
VOL	Low-level output voltage		VIL = VIL max	I _{OL} = 24 mA					0.35	0.5	•
lozh	Off-state output current.		$V_{CC} = MAX,$ $V_{IH} = 2 V,$	V _O = 2.7 V			20			20	μΑ
lozL			VIL = VIL max	V _O = 0.4 V			- 20			- 20	μΑ
11	Input current at maximum input voltage		V _{CC} = MAX,	V _I = 7 V			0.1			0.1	mA
۱н	I _{IH} High-level input current, any input		V _{CC} = MAX,	V _I = 2.7 V			20			20	μΑ
IIL	I _{IL} Low-level input current		V _{CC} = MAX,	$V_1 = 0.4 V$			-0.2			-0.2	mA
los	Short-circuit output	current §	V _{CC} = MAX		-40		-225	-40		-225	mA
	Supply current	obly current Outputs low		'LS540		13	25		13	25	
]	'LS541		18	32		18	32	
loo			V _{CC} = MAX,	'LS540		24	45		24	45	mA
lcc			Outputs open	'LS541		30	52		30	52] ""^
		All outputs		'LS540		30	52		30	52	
		disabled		'LS541		32	55		32	55	

[†]For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.



 $^{^{\}ddagger}$ All typical values are at V_{CC} = 5 V, T_A = 25 °C.

Not more than one output should be shorted at a time, and duration of the short-circuit should not exceed one second.

SN54LS540, SN54LS541, SN74LS540, SN74LS541 OCTAL BUFFERS AND LINE DRIVERS WITH 3-STATE OUTPUTS SDLS180 – AUGUST 1979 – REVISED MARCH 1988

switching characteristics, $V_{CC} = 5 \text{ V}$, $T_A = 25 \,^{\circ}\text{C}$

PARAMETER		TEST CONDITIONS		'LS540			'LS541			
				MIN	TYP	MAX	MIN	TYP	MAX	UNIT
tPLH	Propagation delay time, low-to-high-level output				9	15		9	15	ns
tPHL	Propagation delay time,	C _L = 45 pF,	$R_L = 667 \Omega$,		9	15		10	18	ns
tPZL	high-to-low-level output Output enable time to low level	See Note 2			25	38		25	38	ns
tPZH	Output enable time to high level				15	25		20	32	ns
tPLZ	Output disable time from low level	C _L = 5 pF,	$R_L = 667 \Omega$,		10	18		10	18	ns
^t PHZ	Output disable time from high level	See Note 2			15	25		18	29	ns

NOTE 2: Load circuits and voltage waveforms are shown in Section 1.



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